In re Appln. of Yasuhiro ARAKI Application No. Unassigned

ABSTRACT AMENDMENTS

Replace the Abstract with:

A semiconductor device has a semiconductor substrate \(\frac{1}{2}\); a first interlayer insulating film \(\frac{2}\) formed on the semiconductor substrate, and having first contact holes; first contact plugs \(\frac{12}\) and \(\frac{13}\) formed on the first interlayer insulating film \(\frac{2}\) and having portions buried in the first contact holes and portions \(\frac{\text{protruded}}{\text{protruded}}\) protruding from the surface of the first interlayer insulating film \(\frac{2}{2}\); sidewalls \(\frac{15}{12}\) formed on the sides of the \(\frac{\text{protruded}}{\text{protruded}}\) protruding portions of the first contact plugs \(\frac{12}{12}\) and \(\frac{13}{13}\), and the sidewalls \(\frac{15}{15}\), and having second contact holes; and second contact plugs \(\frac{19}{12}\) and \(\frac{20}{13}\). formed on in the second contact holes, and connected to the first contact plugs \(\frac{12}{12}\) and \(\frac{13}{13}\).